## NSN 5961-01-627-6591

Diode Semiconductor Device - Page 1 of 1



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Overall Length:
Between 1.30 millimeters and 3.70 millimeters
Overall Diameter:
Between 1.30 millimeters and 1.60 millimeters
Power Rating Per Characteristic:
200.0 milliwatts average gate power dissipation
Capacitance Rating In Picofarads:
1.0
Maximum Operating Tempurature Per Measurement Point:
$55.0 \ \mbox{degrees}$ celsius ambient air and 125.0 degrees celsius ambient air
Product Name:
Barrier switching diode
Special Features:
Flange 0.28 to 0.50
Specification Or Standard:
0.05 weight
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0